

1. Record Nr.	UNINA9910830882403321
Titolo	Advances in dielectric materials and electronic devices [[electronic resource]] : proceedings of the 107th Annual Meeting of the American Ceramic Society : Baltimore, Maryland, USA (2005) // editors, K.M. Nair ... [et al.]
Pubbl/distr/stampa	Westerville, Ohio, : American Ceramic Society, c2006
ISBN	1-280-67368-0 9786613650610 1-118-40816-0 1-118-40817-9
Descrizione fisica	1 online resource (336 p.)
Collana	Ceramic transactions ; ; v. 174
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Disciplina	620.1/4047297 620.14047297
Soggetti	Ceramics - Electric properties Electronic ceramics Dielectrics - Materials
Lingua di pubblicazione	Inglese
Formato	Materiale a stampa
Livello bibliografico	Monografia
Note generali	"This volume contains 34 invited and contributed papers from the International Symposium on Advanced Dielectric Materials: Design, Preparation, Processing, Properties and Applications, held during ACerS' 107th Annual Meeting, April 10-13, 2005, at the Baltimore Marriott Waterfront, Baltimore, Md., USA."--Pref.
Nota di bibliografia	Includes bibliographical references and index.
Nota di contenuto	Advances in Dielectric Materials and Electronic Devices; Contents; Preface; Material Design and Synthesis; Molecular Designing of Fine Particles Using Aerosol Synthesis; Size Effect of Dielectric Properties for Barium Titanate Particles and its Model Using Two Factors; Embedded Ceramic Passive on FR-4 Using Aerosol Deposition; Novel Routes to Ferroelectric Gadolinium Molybdenum Oxides; Preparation of High Dispersion TiO ₂ Powders by Chlorideprocess to Synthesize Ultra Fine Dielectric Powders; Two-Phase Ceramic Dielectrics Deposition and Single-Step Processing of YBCO Thick Films for Multilayered ElectronicsLaser Transferred Sol-Gel PZT Thin Films; Synthesis and Characterization of C-N Thin Films Deposited on Si (100)

Wafer by MPCVD; Novel Dielectric Crystals: Ternary Selenides; Aerosol Deposition for Fabrication of High Speed Opticalmicro-Scanner; Processing and Properties; The Effect of Processing, Tantalum-Replacement, and Lanthanum-Doping on the Dielectric Properties of Lead Magnesium Niobate-Lead Titanate Ceramics; Dielectric and Magnetolectric Properties of 1-X NBT - X BF Solid Solutions The PTCR Effect of Donor-Doped Barium Titanate: Origin of the Surface States at the Grain-BoundaryLead-Free Piezoelectric Ceramic Based on $(\text{Bi}_{1/2}\text{Na}_{1/2})\text{Ti}_3(\text{Bi}_{1/2}\text{K}_{1/2})\text{TiO}_3\text{-BaTiO}_3$ Solid Solution; Large Spontaneous Polarizaion in Suprelattice-Structured Bismuth Layerd Ferroelectric Crystals; Impact of $\text{SrRuO}_3/\text{LaNiO}_3$ Doubly-Stacked Bottom Electrode on the Characteristics of c-Axis-Oriented $\text{CaBi}_4\text{Ti}_4\text{O}_{15}$ Films; Complex Permittivity of Calcium Copper Titanate Ceramics with a Bimodal Grain Size Distribution; Dielectric and Pyroelectric Behavior of $(\text{Ba}_{1-x}\text{Sr}_x)\text{TiO}_3$ Composites with Oxide Additives Effect of Porosity on the Electrical Properties of $\text{Y}_2\text{O}_3\text{-SrTiO}_3$ Internal Boundary Layer CapacitorsIsotropic Optical Properties of Epitaxial PLZT Thin Films; Characterization and Application of $\text{Pb}[(\text{Zn}_{1/3}\text{Nb}_{2/3})_{0.91}\text{Ti}_{0.09}]_3\text{O}_3$ Single Crystal with Giant Electromechanical Coupling Factor k_{31} ; Dielectric Properties and Phase Transition In Sb/Mn and La/Mn Codoped BaTiO_3 Ceramics; Processing and Properties of Inorganic/Organic Dielectric Nanocomposites; Sintering Behavior of Ni-Cu-Zn Ferrites for Multilayer Inductors Process Variables, Dielectric Properties, and Microstructures of Multilayer Ceramic Capacitors with Ni Internal ElectrodesApplications; High Performance Barium Strontium Titanate Thin Film Capacitors for Decoupling Applications; Wettability Considerations for Sub-Micron Base Metal Electrodes in BaTiO_3 Multilayer Capacitors; Internal Stress and Capacitance Aging of BME-MLCCS; Piezoceramic Thin-Film Multilayer Resonators on Crystalline Dielectric Substrates High Performance Thin Films for Microwave Phase Shifter Applications: Device Requirements, Material Design, and Process Science Considerations

Sommario/riassunto

This proceedings contains papers presented at the Advanced Dielectric Materials: Design, Preparation, Processing and Applications; and Advanced Dielectrics for Wireless Communications symposia. Topics include design of material, materials synthesis and processing, processing-microstructure-property relationship, multilayer device materials, thin and thick films, device applications, low temperature co-fired ceramics (LTCC)for multilayer devices, microwave dielectric materials and much more.
